

10kV 5mA HIGH VOLTAGE DIODES

ESJA08-10 is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

■ Features

- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

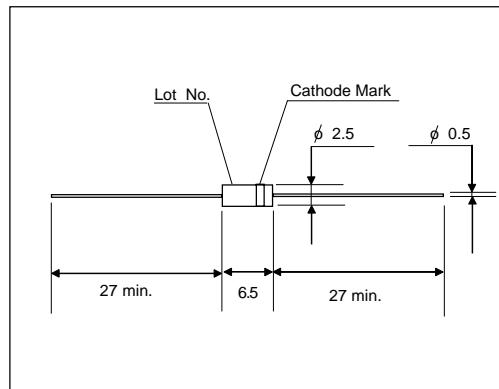
■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

■ Outline Drawings : mm



■ Cathode Mark

Type	Mark
ESJA08-10	

Items	Symbols	Condition	ESJA08-10	Units
Repetitive Peak Reverse Voltage	V_{RRM}		10	kV
Average Output Current	I_o	$T_a=25^\circ C$, Resistive Load	5.0	mA
Surge Current	I_{FSM}		0.5	A_{peak}
Junction Temperature	T_j		125	$^\circ C$
Allowable Operation Case Temperature	T_c		125	$^\circ C$
Storage Temperature	T_{stg}		-40 to +125	$^\circ C$

- Electrical Characteristics ($T_a=25^\circ C$ Unless otherwise specified)

Items	Symbols	Conditions	ESJA08-10	Units
Maximum Forward Voltage Drop	V_F	at $25^\circ C$, $I_F = I_{F(AV)}$	30	V
Maximum Reverse Current	I_{R1}	at $25^\circ C$, $V_R = V_{RRM}$	2.0	μA
	I_{R2}	at $100^\circ C$, $V_R = V_{RRM}$	5.0	μA
Maximum Reverse Recovery Time	T_{rr}	at $25^\circ C$	80	nS
Junction Capacitance	C_j	at $25^\circ C$, $V_R=0V$, $f=1MHz$	2.0	pF